

SN54LVT16245B...WD PACKAGE

SN74LVT16245B... DGG, DGV, OR DL PACKAGE

(TOP VIEW)

1DIR 1

1B1 **1**2

1B2 3

GND 14

1B3 **1**5

1B4 **6** 

V<sub>CC</sub> 7

1B5 8

1B6 9

GND 10

1B8 🛛 12

2B1 13

2B2 14

GND 115

2B3 16

2B4 17

V<sub>CC</sub> [] 18

2B5 19

2B6 20

GND 21

2B7 22

2B8 23

2DIR 🛛 24

1B7 🛛 11 48 1 1 OE

47 1A1

46 🛛 1A2

45 GND

44 **1**A3

43 🛛 1A4

42 V<sub>CC</sub>

41 1A5

40 1A6

39 GND

38 1A7

37 **1**A8

36 2A1

35 2A2

34 GND

33 2A3

32 2A4

31 V<sub>CC</sub>

30 2A5

29 2A6

28 GND

27 2A7

26 2A8

25 20E

#### FEATURES

- Member of the Texas Instruments Widebus™ Family
- State-of-the-Art Advanced BiCMOS Technology (ABT) Design for 3.3-V Operation and Low Static-Power Dissipation
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V<sub>cc</sub>)
- Support Unregulated Battery Operation Down ٠ to 2.7 V
- Typical V<sub>OLP</sub> (Output Ground Bounce) <0.8 V ٠ at  $V_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- I<sub>off</sub> and Power-Up 3-State Support Hot Insertion
- Distributed V<sub>CC</sub> and GND Pins Minimize • **High-Speed Switching Noise**
- Flow-Through Architecture Optimizes PCB Layout
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Protection Exceeds JESD 22** 
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

### **DESCRIPTION/ORDERING INFORMATION**

#### **ORDERING INFORMATION**

T <sub>A</sub>	PACKAG	6E <sup>(1)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	FBGA – GRD	Reel of 1000	SN74LVT16245BGRDR	- VD245B
	FBGA – ZRD (Pb-free)	Reel 01 1000	SN74LVT16245BZRDR	VD243D
		Tube of 25	SN74LVT16245BDL	
	SSOP – DL		SN74LVT16245BDLG4	LVT16245B
	330F - DL	Reel of 1000	SN74LVT16245BDLR	LV110243D
–40°C to 85°C		Reel 01 1000	74LVT16245BDLRG4	
-40°C 10 85°C		Reel of 2000	SN74LVT16245BDGGR	
	TSSOP – DGG	Reel 01 2000	74LVT16245BDGGRE4	– LVT16245B
		Deal of 2000	SN74LVT16245BDGVR	
	TVSOP – DGV	Reel of 2000	74LVT16245BDGVRE4	– VD245B
	VFBGA – GQL	Deal of 1000	SN74LVT16245BGQLR	
	VFBGA – ZQL (Pb-free)	Reel of 1000	SN74LVT16245BZQLR	– VD245B
–55°C to 125°C	CFP – WD	Tube	SNJ54LVT16245BWD	SNJ54LVT16245BWD

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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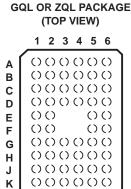
### DESCRIPTION/ORDERING INFORMATION (CONTINUED)

The 'LVT16245B devices are 16-bit (dual-octal) noninverting 3-state transceivers designed for low-voltage (3.3-V) V<sub>CC</sub> operation, but with the capability to provide a TTL interface to a 5-V system environment.

These devices are designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input and the output-enable (OE) input activate either the B-port outputs or the A-port outputs or place both output ports into the high-impedance mode. The device transmits data from the A bus to the B bus when the B-port outputs are activated, and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports is always active and must have a logic HIGH or LOW level applied to prevent excess  $I_{CC}$  and  $I_{CCZ}$ .

When  $V_{CC}$  is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V,  $\overline{OE}$  should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for hot-insertion applications using I<sub>off</sub> and power-up 3-state. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.



		(	(TC	P	VIE	W)		
	_	1	2	3	4	5	6	
	ſ	()	()	()	()	()	0	
3		()	()	()	()	()	()	L
		()	()	()	()	()	()	L
		()	()	0	()	()	()	l
		()	()			$\bigcirc$	()	l
-		()	()			()	()	L
3		()	()	()	()	()	()	L
1		()	()	()	()	()	()	
1		()	$\bigcirc$	()	$\bigcirc$	$\bigcirc$	()	
(		()	0	()	0	()	()	

TERMINAL ASSIGNMENTS <sup>(1)</sup>
(56-Ball GQL/ZQL Package)

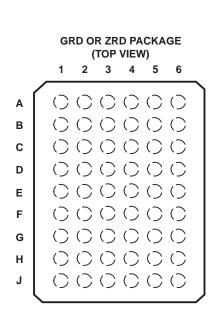
	1	2	3	4	5	6
Α	1DIR	NC	NC	NC	NC	1 <del>0E</del>
В	1B2	1B1	GND	GND	1A1	1A2
С	1B4	1B3	V <sub>CC</sub>	V <sub>CC</sub>	1A3	1A4
D	1B6	1B5	GND	GND	1A5	1A6
Е	1B8	1B7			1A7	1A8
F	2B1	2B2			2A2	2A1
G	2B3	2B4	GND	GND	2A4	2A3
н	2B5	2B6	V <sub>CC</sub>	V <sub>CC</sub>	2A6	2A5
J	2B7	2B8	GND	GND	2A8	2A7
к	2DIR	NC	NC	NC	NC	2 <del>0E</del>

(1) NC - No internal connection

#### TERMINAL ASSIGNMENTS<sup>(1)</sup> (54-Ball GRD/ZRD Package)

	•		<b>U</b> ,							
	1	2	3	4	5	6				
Α	1B1	NC	1DIR	1 <del>0E</del>	NC	1A1				
В	1B3	1B2	NC	NC	1A2	1A3				
С	1B5	1B4	V <sub>CC</sub>	V <sub>CC</sub>	1A4	1A5				
D	1B7	1B6	GND	GND	1A6	1A7				
Е	2B1	1B8	GND	GND	1A8	2A1				
F	2B3	2B2	GND	GND	2A2	2A3				
G	2B5	2B4	V <sub>CC</sub>	V <sub>CC</sub>	2A4	2A5				
н	2B7	2B6	NC	NC	2A6	2A7				
J	2B8	NC	2DIR	2 <del>0E</del>	NC	2A8				

(1) NC - No internal connection

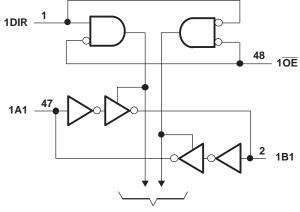


### FUNCTION TABLE<sup>(1)</sup> (each 8-bit section)

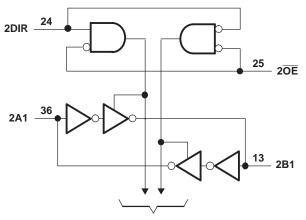
CONTROL INPUTS		OUTPUT C	CIRCUITS	OPERATION
ŌĒ	DIR	A PORT	<b>B PORT</b>	OPERATION
L	L	Enabled	Hi-Z	B data to A bus
L	Н	Hi-Z	Enabled	A data to B bus
н	Х	Hi-Z	Hi-Z	Isolation

(1) Input circuits of the data I/Os always are active.

#### LOGIC DIAGRAM (POSITIVE LOGIC)



To Seven Other Channels



**To Seven Other Channels** 

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### Absolute Maximum Ratings<sup>(1)</sup>

over recommended operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	4.6	V
VI	Input voltage range <sup>(2)</sup>		-0.5	7	V
Vo	Voltage range applied to any output in the high-impedanc	ce or power-off state <sup>(2)</sup>	-0.5	7	V
Vo	Voltage range applied to any output in the high state <sup>(2)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
	Comment into any contract in the law state	SN54LVT16245B		96	
I <sub>O</sub>	Current into any output in the low state	SN74LVT16245B		128	mA
	$\mathbf{O}_{1}$	SN54LVT16245B		48	
1 <sub>0</sub>	Current into any output in the high state <sup>(3)</sup>	SN74LVT16245B		64	mA
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
		DGG package		70	
		DGV package		58	
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DL package		63	°C/W
		GQL/ZQL package		42	
		GRD/ZRD package		36	
T <sub>stg</sub>	Storage temperature range	·	-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed. (3) This current flows only when the output is in the high state and  $V_O > V_{CC}$ . (4) The package thermal impedance is calculated in accordance with JESD 51-7.

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# Recommended Operating Conditions<sup>(1)</sup>

			SN54LVT162	245B <sup>(2)</sup>	SN74LVT	16245B	UNIT
			MIN	MAX	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2.7	3.6	2.7	3.6	V
VIH	High-level input voltage		2		2		V
VIL	Low-level input voltage			0.8		0.8	V
VI	Input voltage			5.5		5.5	V
I <sub>OH</sub>	High-level output current			-24		-32	mA
I <sub>OL</sub>	Low-level output current			48		64	mA
$\Delta t / \Delta v$	Input transition rise or fall rate	Outputs enabled		10		10	ns/V
$\Delta t / \Delta V_{CC}$	Power-up ramp rate		200		200		μs/V
T <sub>A</sub>	Operating free-air temperature		-55	125	-40	85	°C

 All unused or undriven (floating) inputs (I/Os) of the device must be held at logic HIGH or LOW (preferably V<sub>CC</sub> or GND) to ensure proper device operation and minimize power. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

(2) Product preview

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### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEOT	CONDITIONS	SN54L	_VT16245B	(1)	SN74L	UNIT		
	ARAMETER	IEST	CONDITIONS	MIN	TYP <sup>(2)</sup>	MAX	MIN	TYP <sup>(2)</sup>	MAX	UNIT
V <sub>IK</sub>		V <sub>CC</sub> = 2.7 V,	I <sub>I</sub> = -18 mA			-1.2			-1.2	V
		V <sub>CC</sub> = 2.7 to 3.6 V,	I <sub>OH</sub> = −100 μA	V <sub>CC</sub> - 0.2			$V_{CC} - 0.2$			
		V <sub>CC</sub> = 2.7 V,	I <sub>OH</sub> = -8 mA	2.4			2.4			V
V <sub>OH</sub>		V 2V	I <sub>OH</sub> = -24 mA	2						V
		$V_{CC} = 3 V$	I <sub>OH</sub> = -32 mA				2			
		V 07V	I <sub>OL</sub> = 100 μA			0.2			0.2	
		$V_{CC} = 2.7 V$	I <sub>OL</sub> = 24 mA			0.5			0.5	
v			I <sub>OL</sub> = 16 mA			0.4			0.4	V
V <sub>OL</sub>		V 2.V	I <sub>OL</sub> = 32 mA			0.5			0.5	v
		$V_{CC} = 3 V$	I <sub>OL</sub> = 48 mA			0.55				
			I <sub>OL</sub> = 64 mA						0.55	
	Control V <sub>0</sub>	V <sub>CC</sub> = 3.6 V,	$V_{I} = V_{CC}$ or GND			±1			±1	
	inputs	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V <sub>I</sub> = 5.5 V			10			10	
I <sub>I</sub>			V <sub>I</sub> = 5.5 V			20			20	μA
	A or B port <sup>(3)</sup>	$V_{CC} = 3.6 V$	$V_{I} = V_{CC}$			5			1	
	port		$V_{I} = 0$			-5			-5	
I <sub>off</sub>		$V_{\rm CC} = 0,$	$V_{I}$ or $V_{O}$ = 0 to 4.5 V						±100	μA
I <sub>OZP</sub>	U	$\frac{V_{CC}}{OE} = 0$ to 1.5 V, V <sub>O</sub> $\overline{OE} = $ don't care	= 0.5 V to 3 V,			±100 <sup>(4)</sup>			±100	μA
I <sub>OZP</sub>	D	$\frac{V_{CC}}{OE}$ = 1.5 V to 0, V <sub>O</sub> $\overline{OE}$ = don't care	= 0.5 V to 3 V,			±100 <sup>(4)</sup>			±100	μΑ
		V <sub>CC</sub> = 3.6 V,	Outputs high			0.19			0.19	
Icc		$I_{0} = 0,$	Outputs low			5			5	mA
		$V_{I} = V_{CC}$ or GND	Outputs disabled			0.19			0.19	
ΔI <sub>CC</sub>	<sub>5</sub> (5)	$V_{CC}$ = 3 V to 3.6 V, 0 Other inputs at V <sub>CC</sub>	One input at V <sub>CC</sub> – 0.6 V, or GND			0.2			0.2	mA
Ci		V <sub>I</sub> = 3 V or 0			4			4		pF
Cio		$V_0 = 3 V \text{ or } 0$			10			10		pF
-										

Product preview
All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.
Unused pins at V<sub>CC</sub> or GND.
On products compliant to MIL-PRF-38535, this parameter is not production tested.

(5) This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V<sub>CC</sub> or GND.



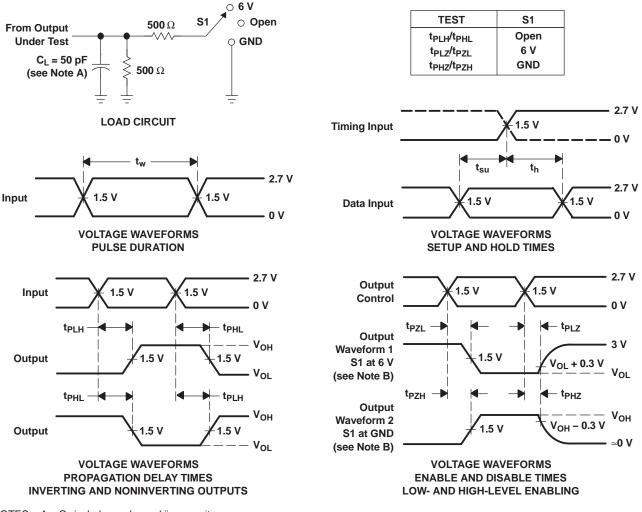
# **Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Figure 1)

			SN	54LVT1	6245B <sup>(1)</sup>	)		SN74I	_VT162	245B		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 3 ± 0.3	8.3 V V	V <sub>CC</sub> =	2.7 V	v	cc = 3.3 ± 0.3 V	v	V <sub>CC</sub> =	2.7 V	UNIT
			MIN	MAX	MIN	MAX	MIN	TYP <sup>(2)</sup>	MAX	MIN	MAX	
t <sub>PLH</sub>	A or B	B or A	0.5	4.5		4.6	1.5	2.3	3.3		3.7	-
t <sub>PHL</sub>	AUD	BOIA	0.5	4.4		3.9	1.3	2.1	3.3		3.5	ns
t <sub>PZH</sub>	OE	A or B	0.5	6.5		6.6	1.5	2.8	4.5		5.3	-
t <sub>PZL</sub>	0E	AUB	0.5	5.4		6.2	1.6	2.9	4.6		5.2	ns
t <sub>PHZ</sub>	OE	A or B	1	6.8		7	2.3	3.7	5.1		5.5	
t <sub>PLZ</sub>	UE	AUB	1	6.2		6.3	2.2	3.5	5.1		5.4	ns
t <sub>sk(LH)</sub>									0.5			
t <sub>sk(HL)</sub>									0.5			ns

(1) Product preview (2) All typical values are at V\_{CC} = 3.3 V, T\_A = 25^{\circ}C.

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### PARAMETER MEASUREMENT INFORMATION

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STRUMENTS www.ti.com

NOTES: A. C<sub>1</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>0</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.

#### Figure 1. Load Circuit and Voltage Waveforms



6-Feb-2020

### PACKAGING INFORMATION

Orderable Device	Status	Package Type	-	Pins		Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
74LVT16245BDGGRE4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT16245B	Samples
SN74LVT16245BDGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT16245B	Samples
SN74LVT16245BDGVR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VD245B	Samples
SN74LVT16245BDL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT16245B	Samples
SN74LVT16245BDLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT16245B	Samples
SN74LVT16245BZQLR	LIFEBUY	BGA MICROSTAR JUNIOR	ZQL	56	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	VD245B	
SN74LVT16245BZRDR	LIFEBUY	BGA MICROSTAR JUNIOR	ZRD	54	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	VD245B	

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



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# PACKAGE OPTION ADDENDUM

6-Feb-2020

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVT16245BDGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1
SN74LVT16245BDGVR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1
SN74LVT16245BDLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1
SN74LVT16245BZQLR	BGA MI CROSTA R JUNI OR	ZQL	56	1000	330.0	16.4	4.8	7.3	1.5	8.0	16.0	Q1
SN74LVT16245BZRDR	BGA MI CROSTA R JUNI OR	ZRD	54	1000	330.0	16.4	5.8	8.3	1.55	8.0	16.0	Q1

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# PACKAGE MATERIALS INFORMATION

31-May-2019



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVT16245BDGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0
SN74LVT16245BDGVR	TVSOP	DGV	48	2000	367.0	367.0	38.0
SN74LVT16245BDLR	SSOP	DL	48	1000	367.0	367.0	55.0
SN74LVT16245BZQLR	BGA MICROSTAR JUNIOR	ZQL	56	1000	350.0	350.0	43.0
SN74LVT16245BZRDR	BGA MICROSTAR JUNIOR	ZRD	54	1000	350.0	350.0	43.0

DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.



# **MECHANICAL DATA**

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

### DGV (R-PDSO-G\*\*)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



# **MECHANICAL DATA**

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

#### DGG (R-PDSO-G\*\*)

### PLASTIC SMALL-OUTLINE PACKAGE

**48 PINS SHOWN** 



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



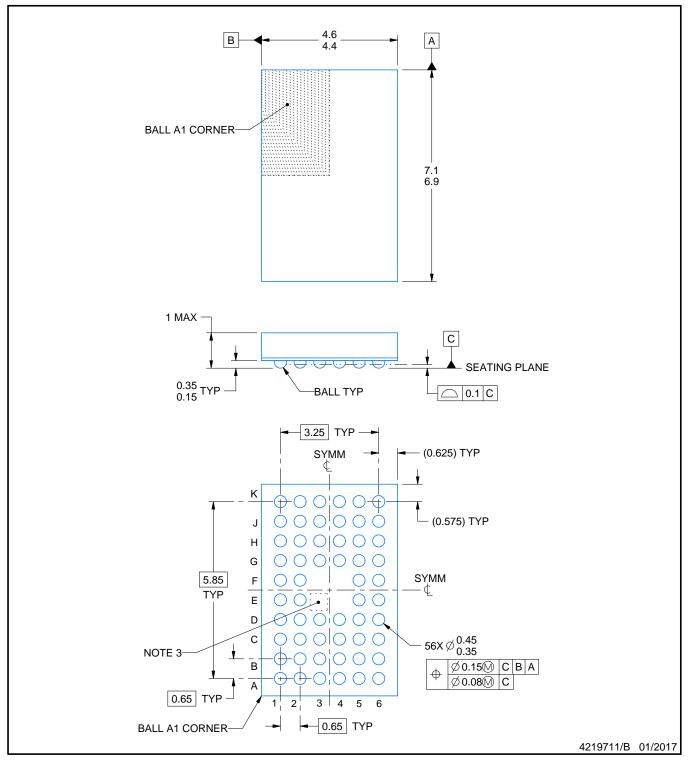
# **ZQL0056A**



# **PACKAGE OUTLINE**

### JRBGA - 1 mm max height

PLASTIC BALL GRID ARRAY



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. No metal in this area, indicates orientation.

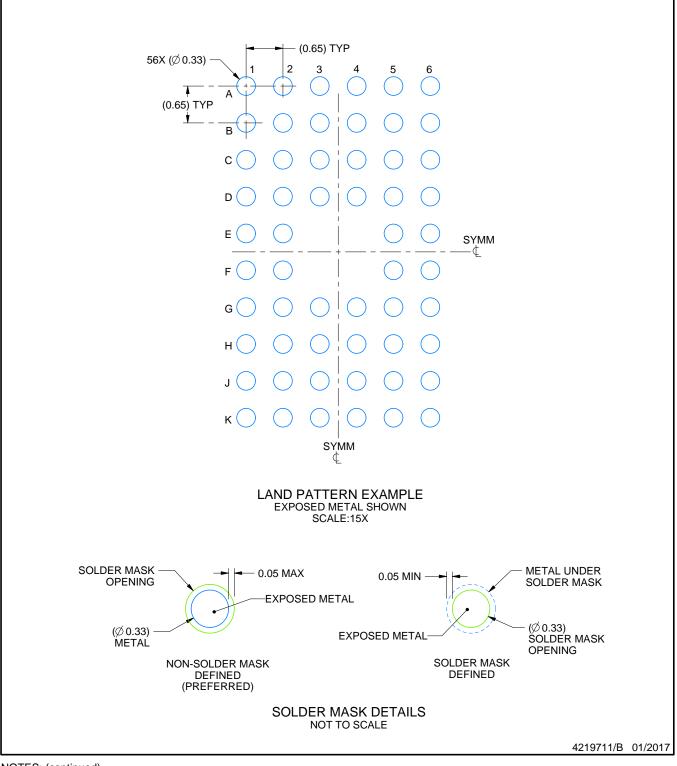


# ZQL0056A

# **EXAMPLE BOARD LAYOUT**

### JRBGA - 1 mm max height

PLASTIC BALL GRID ARRAY



NOTES: (continued)

4. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For information, see Texas Instruments literature number SPRAA99 (www.ti.com/lit/spraa99).

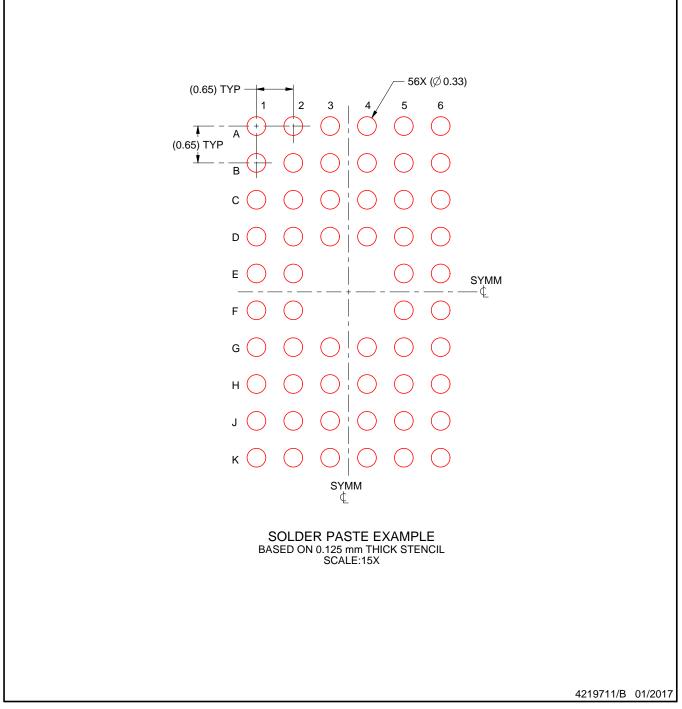


# ZQL0056A

# **EXAMPLE STENCIL DESIGN**

### JRBGA - 1 mm max height

PLASTIC BALL GRID ARRAY



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



ZRD (R-PBGA-N54)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

Falls within JEDEC MO-205 variation DD.

D. This package is lead-free. Refer to the 54 GRD package (drawing 4204759) for tin-lead (SnPb).



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